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TOSHIBA Photocoupler GaA{As Ired & Photo-IC

TLP2200

Isolated Buss Driver High Speed Line Receiver Microprocessor System Interfaces MOS FET Gate Driver Direct Replacement For HCPL-2200

The TOSHIBA TLP2200 consists of a GaAlAs light emitting diode and integrated high gain, high speed photodetector.

This unit is 8-lead DIP package.

The detector has a three state output stage that eliminates the need for pull-up resistor, and built-in schmitt trigger. The detector IC has an internal shield that provides a guaranteed common mode transient immunity of 1000V / µs.

- Input current: I_F = 1.6mA
- Power supply voltage: $V_{CC} = 4.5 \sim 20V$
- Switching speed: 2.5MBd guaranteed
- Common mode transient immunity: ±1000V / µs (min.)
- Guaranteed performance over temp: 0~85°C
- Isolation voltage: 2500Vrms(min.)
- UL recognized: UL1577, file No. E67349

Truth Table (positive logic)

Input	Enable	Output
Н	Н	Z
L	Н	Z
Н	L	Н
L	L	L



Weight: 0.54 g

Pin Configuration (top view)



Schematic



Unit in mm

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Input current, on	I _{F(ON)}	1.6		5	mA
Input current, off	I _{F(OFF)}	0		0.1	mA
Supply voltage	V _{CC}	4.5		20	V
Enable voltage high	V _{EH}	2.0		20	V
Enable voltage low	V _{EL}	0		0.8	V
Fan out (TTL load)	Ν			4	_
Operating temperature	T _{opr}	0		85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Absolute Maximum Ratings (no derating required up to 70°C)

	Characteristic	Symbol	Rating	Unit
Δ	Forward current	١ _F	10	mA
ш	Peak transient forward current (Note 1)	I _{FPT}	1	А
_	Reverse voltage	V _R	5	V
L	Output current	Ι _Ο	25	mA
c t o	Supply voltage	V _{CC}	-0.5~20	V
Ð	Output voltage	Vo	-0.5~20	V
e t	Three state enable voltage	VE	-0.5~20	V
	Total package power dissipation (Note 2)	PT	210	mW
Ope	rating temperature range	T _{opr}	-40~85	°C
Stor	age temperature range	T _{stg}	-55~125	°C
Lead	d solder temperature (10s) (**)	T _{sol}	260	°C
Isola	tion voltage (AC 1min., R.H. ≤ 60%,Ta = 25°C) (Note 3)	BVS	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- (Note 1) Pulse width 1µs 300pps.
- (Note 2) Derate 4.5mW / °C above 70°C ambient temperature.
- (Note 3) Device considered a two terminal device: Pins 1, 2, 3 and 4 shorted together, and pins 5,6,7 and 8 shorted together
 - (**) 1.6mm below seating plane.

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Electrical Characteristics (unless otherwise specified, Ta = 0~85°C,V_{CC} = 4.5~20V, $I_{F(ON)}$ = 1.6~5mA, $I_{F(OFF)}$ = 0~0.1mA, V_{EL} = 0~0.8V,V_{EH} = 2.0~20V)

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Characteristic	Symbol	Test C	condition	Min.	Тур.*	Max.	Unit
Output leakage current (V _O > V _{CC})	IOHH	I _F = 5mA, V _{CC} = 4.5V	V _O = 5.5V V _O = 20V		2	100 500	μA
Logic low output voltage	V _{OL}	I _{OL} = 6.4mA (4 T	TL load)	-	0.32	0.5	V
Logic high output voltage	V _{OH}	I _{OH} = -2.6mA		2.4	3.4	_	V
Logic low enable current	I _{EL}	V _E = 0.4V		-	-0.13	-0.32	mA
Logic high enable current	I _{EH}	V _E = 2.7V V _E = 5.5V V _E = 20V			— — 0.01	20 100 250	μΑ
Logic low enable voltage	V_{EL}		_	—	—	0.8	V
Logic high enable voltage	V _{EH}		_	2.0	_	_	V
Logic low supply current	I _{CCL}	I _F = 0mA V _E = don't care	$V_{CC} = 5.5V$ $V_{CC} = 20V$	_	5 5.6	6.0 7.5	mA
Logic high supply current	ICCH	I _F = 5mA V _E = don't care	$V_{CC} = 5.5V$ $V_{CC} = 20V$		2.5 2.8	4.5 6.0	mA
High impedance state output current	I _{OZL}	I _F = 5mA V _E = 2V	V _O = 0.4V	_	1	-20	
	IOZH	I _F = 0mA V _E = 2V	$V_{O} = 2.4V$ $V_{O} = 5.5V$ $V_{O} = 20V$	_		20 100 500	μA
Logic low short circuit output current (Note 4)	I _{OSL}	I _F = 0mA	$V_0 = 20V$ $V_0 = V_{CC} = 5.5V$ $V_0 = V_{CC} = 20V$	 25 40	55 80		mA
Logic high short circuit output current (Note 4)	I _{OSH}	I _F = 5mA V _O = GND	$\frac{V_{CC} = 5.5V}{V_{CC} = 20V}$	-10 -25	-25 -60		mA
Input current hysteresis	I _{HYS}	V _{CC} = 5V		_	0.05	_	mA
Input forward voltage	VF	I _F = 5mA, Ta = 2	5°C	_	1.55	1.7	V
Temperature coefficient of forward voltage	ΔV _F / ΔTa	I _F = 5mA		_	-2.0	_	mV / °C
Input reverse breakdown voltage	BV _R	I _R = 10μA, Ta = 25°C		5	_	_	V
Input capacitance	C _{IN}	V _F = 0V, f = 1MHz, Ta = 25°C		_	45	_	pF
Resistance (input-output)	R _{I–O}	V _{I–O} = 500V R.H	. ≤ 60% (Note 3)	5×10 ¹⁰	10 ¹⁴	_	Ω
Capacitance (input-output)	C _{I–O}	V _{I-O} = 0V, f = 1N	IHz (Note 3)	_	0.6	_	pF

(**) All typ. values are at Ta = 25°C, V_{CC} = 5V, $I_{F(ON)}$ = 3mA unless otherwise specified.

Switching Characteristics (unless otherwise specified, Ta = 0~85°C,V_{CC} = 4.5~20V,I_{F(ON)} = 1.6~5mA,I_{F(OFF)} = 0~0.1mA)

Characteristic		Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit
Propagation delay time to logic high output level		^t pLH		Without peaking capacitor C ₁	_	235	_	ns
	(Note 5)			With peaking capacitor C1	_	_	400	
Propagation delay time to logic low output level		t _{pHL}	1	Without peaking capacitor C1	_	250	_	ns
	(Note 5)			With peaking capacitor C1	—		400	
Output rise time (10-90%)		t _r			_	35	_	ns
Output fall time (90-10%)		t _f		—	_	20	_	ns
Output enable time to logic high		t _{pZH}		_	_	_	—	ns
Output enable time to logic low		t _{pZL}	2	_	_	_	_	ns
Output disable time from logic high		t _{pHZ}	2	_	_	_	_	ns
Output disable time from logic low		t _{pLZ}		_	_	_	_	ns
Common mode transient immunity at logic high output	(Note 6)	CM _H	3	I _F = 1.6mA, V _{CM} = 50V, Ta = 25°C	-1000	_	_	V / µs
Common mode transient immunity at logic low output	(Note 6)	CML	3	I _F = 0mA, V _{CM} = 50V, Ta = 25°C	1000	_	_	V / µs

(*) All typ. values are at Ta = 25° C, V_{CC} = 5V, I_{F(ON)} = 3mA unless otherwise specified.

(Note 4) Duration of output short circuit time should not exceed 10ms.

(Note 5) The t_{pLH} propagation delay is measured from the 50% point on the leading edge of the input pulse to the 1.3V point on the leading edge of the output pulse.

The t_{pHL} propagation delay is measured from the 50% point on the trailing edge of the input pulse to the 1.3V point on the trailing edge of the output pulse.

(Note 6) CM_L is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic low state ($V_O \le 0.8V$). CM_H is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic high state ($V_O \le 2.0V$).

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Test Circuit 1

tpHL, tpLH, tr and tf



R ₁	2.15kΩ	1.1kΩ	681Ω
I _F (ON)	1.6mA	3mA	5mA



 C_1 is peaking capacitor. The probe and jig capacitances are include in $C_1.$ C_L is approximately 15pF which includes probe and stray wiring capacitance.

Test Circuit 2 t_{pHZ} , t_{pZH} , t_{pLZ} and t_{pZL}





 $\ensuremath{\mathsf{C}}\xspace_L$ is approximately 15pF which includes probe and stray wiring capacitance.

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Test Circuit 3 Common Mode Transient Immunity



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